

Important notice

Dear Customer,

On 7 February 2017 the former NXP Standard Product business became a new company with the tradename **Nexperia**. Nexperia is an industry leading supplier of Discrete, Logic and PowerMOS semiconductors with its focus on the automotive, industrial, computing, consumer and wearable application markets

In data sheets and application notes which still contain NXP or Philips Semiconductors references, use the references to Nexperia, as shown below.

Instead of <http://www.nxp.com>, <http://www.philips.com/> or <http://www.semiconductors.philips.com/>, use <http://www.nexperia.com>

Instead of sales.addresses@www.nxp.com or sales.addresses@www.semiconductors.philips.com, use salesaddresses@nexperia.com (email)

Replace the copyright notice at the bottom of each page or elsewhere in the document, depending on the version, as shown below:

- © NXP N.V. (year). All rights reserved or © Koninklijke Philips Electronics N.V. (year). All rights reserved

Should be replaced with:

- © **Nexperia B.V. (year). All rights reserved.**

If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via salesaddresses@nexperia.com). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia



PESDxS1UL series

Unidirectional ESD protection diodes

Rev. 3 — 25 October 2011

Product data sheet

1. Product profile

1.1 General description

Unidirectional ElectroStatic Discharge (ESD) protection diodes in a SOD882 leadless ultra small Surface Mounted Device (SMD) plastic package designed to protect one signal line from the damage caused by ESD and other transients.

1.2 Features and benefits

- Ultra small SMD plastic package
- ESD protection of one line
- Max. peak pulse power: $P_{PP} = 150 \text{ W}$
- Low clamping voltage: $V_{CL} = 20 \text{ V}$
- AEC-Q101 qualified
- Ultra low leakage current: $I_{RM} < 700 \text{ nA}$
- ESD protection up to 30 kV
- IEC 61000-4-2; level 4 (ESD)
- IEC 61000-4-5; (surge); I_{PP} up to 15 A

1.3 Applications

- Computers and peripherals
- Audio and video equipment
- Parallel ports
- Communication systems
- High-speed data lines

1.4 Quick reference data



Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{RWM}	reverse standoff voltage					
	PESD3V3S1UL		-	-	3.3	V
	PESD5V0S1UL		-	-	5.0	V
	PESD12VS1UL		-	-	12	V
	PESD15VS1UL		-	-	15	V
	PESD24VS1UL		-	-	24	V
C_d	diode capacitance	$f = 1 \text{ MHz}; V_R = 0 \text{ V}$				
	PESD3V3S1UL		-	207	300	pF
	PESD5V0S1UL		-	152	200	pF
	PESD12VS1UL		-	38	75	pF
	PESD15VS1UL		-	32	70	pF
	PESD24VS1UL		-	23	50	pF



2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	cathode	 <p>Transparent top view</p>	 sym035
2	anode		

[1] The marking bar indicates the cathode.

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PESD3V3S1UL	-	leadless ultra small plastic package; 2 terminals; body 1.0 × 0.6 × 0.5 mm	SOD882
PESD5V0S1UL			
PESD12VS1UL			
PESD15VS1UL			
PESD24VS1UL			

4. Marking

Table 4. Marking codes

Type number	Marking code
PESD3V3S1UL	G1
PESD5V0S1UL	G2
PESD12VS1UL	G3
PESD15VS1UL	G4
PESD24VS1UL	G5

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
P _{PP}	peak pulse power	t _p = 8/20 μs	[1]	-	150 W
I _{PP}	peak pulse current	t _p = 8/20 μs	[1]		
	PESD3V3S1UL		-	15	A
	PESD5V0S1UL		-	15	A
	PESD12VS1UL		-	5	A
	PESD15VS1UL		-	5	A
	PESD24VS1UL		-	3	A
T _j	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

[1] Non-repetitive current pulse 8/20 μs exponential decay waveform according to IEC 61000-4-5.

Table 6. ESD maximum ratings

Symbol	Parameter	Conditions	Min	Max	Unit
V _{ESD}	electrostatic discharge voltage	IEC 61000-4-2 (contact discharge)	[1]		
	PESD3V3S1UL		-	30	kV
	PESD5V0S1UL		-	30	kV
	PESD12VS1UL		-	30	kV
	PESD15VS1UL		-	30	kV
	PESD24VS1UL		-	23	kV
	PESDxS1UL series	MIL-STD-883 (human body model)	-	10	kV

[1] Device stressed with ten non-repetitive ESD pulses.

Table 7. ESD standards compliance

Standard	Conditions
IEC 61000-4-2; level 4 (ESD)	> 15 kV (air); > 8 kV (contact)
MIL-STD-883; class 3B (human body model)	> 8 kV

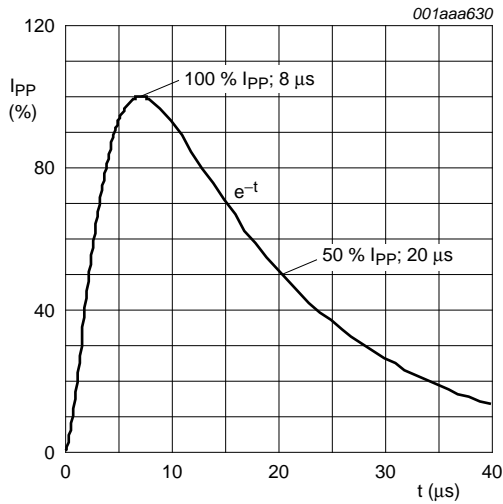


Fig 1. 8/20 μs pulse waveform according to IEC 61000-4-5

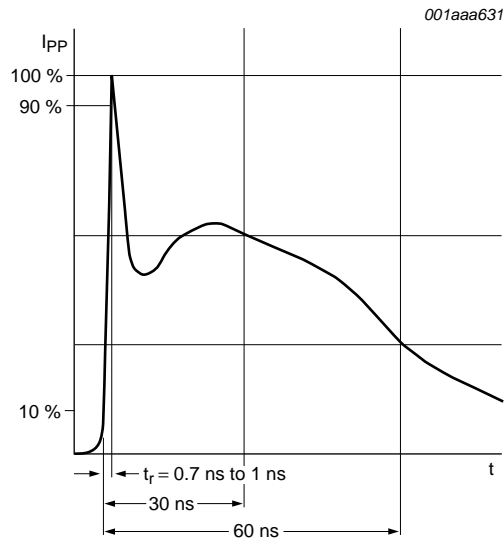


Fig 2. ESD pulse waveform according to IEC 61000-4-2

6. Characteristics

Table 8. Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified

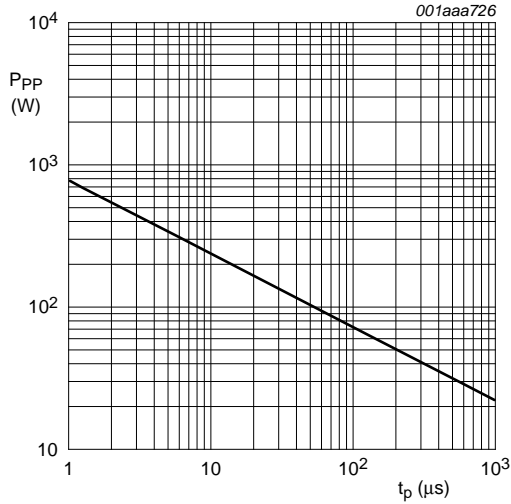
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{RWM}	reverse standoff voltage					
	PESD3V3S1UL		-	-	3.3	V
	PESD5V0S1UL		-	-	5.0	V
	PESD12VS1UL		-	-	12	V
	PESD15VS1UL		-	-	15	V
I_{RM}	reverse leakage current					
	PESD3V3S1UL	$V_{RWM} = 3.3\text{ V}$	-	0.7	2	μA
	PESD5V0S1UL	$V_{RWM} = 5.0\text{ V}$	-	0.1	1	μA
	PESD12VS1UL	$V_{RWM} = 12\text{ V}$	-	< 1	50	nA
	PESD15VS1UL	$V_{RWM} = 15\text{ V}$	-	< 1	50	nA
V_{BR}	breakdown voltage	$I_R = 5\text{ mA}$	[1]			
	PESD3V3S1UL		5.2	5.6	6.0	V
	PESD5V0S1UL		6.4	6.8	7.2	V
	PESD12VS1UL		14.7	15.0	15.3	V
	PESD15VS1UL		17.6	18.0	18.4	V
	PESD24VS1UL		26.5	27.0	27.5	V

Table 8. Characteristics ...continued
T_{amb} = 25 °C unless otherwise specified

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
C _d	diode capacitance	f = 1 MHz; V _R = 0 V				
	PESD3V3S1UL		-	207	300	pF
	PESD5V0S1UL		-	152	200	pF
	PESD12VS1UL		-	38	75	pF
	PESD15VS1UL		-	32	70	pF
	PESD24VS1UL		-	23	50	pF
V _{CL}	clamping voltage		[2]			
	PESD3V3S1UL	I _{PP} = 1 A	-	-	8	V
		I _{PP} = 15 A	-	-	20	V
	PESD5V0S1UL	I _{PP} = 1 A	-	-	9	V
		I _{PP} = 15 A	-	-	20	V
	PESD12VS1UL	I _{PP} = 1 A	-	-	19	V
		I _{PP} = 5 A	-	-	35	V
	PESD15VS1UL	I _{PP} = 1 A	-	-	23	V
		I _{PP} = 5 A	-	-	40	V
	PESD24VS1UL	I _{PP} = 1 A	-	-	36	V
I _{PP} = 3 A		-	-	70	V	
r _{dif}	differential resistance					
	PESD3V3S1UL	I _R = 1 mA	-	-	400	Ω
	PESD5V0S1UL	I _R = 1 mA	-	-	80	Ω
	PESD12VS1UL	I _R = 1 mA	-	-	200	Ω
	PESD15VS1UL	I _R = 1 mA	-	-	225	Ω
	PESD24VS1UL	I _R = 0.5 mA	-	-	300	Ω

[1] Pulse test: t_p ≤ 300 μs; duty cycle ≤ 0.02.

[2] Non-repetitive current pulse 8/20 μs exponential decay waveform according to IEC 61000-4-5.



$T_{amb} = 25\text{ }^{\circ}\text{C}$

Fig 3. Peak pulse power as a function of exponential pulse duration; typical values

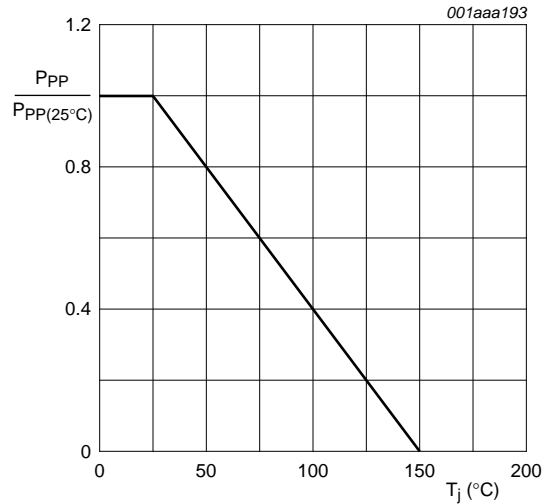
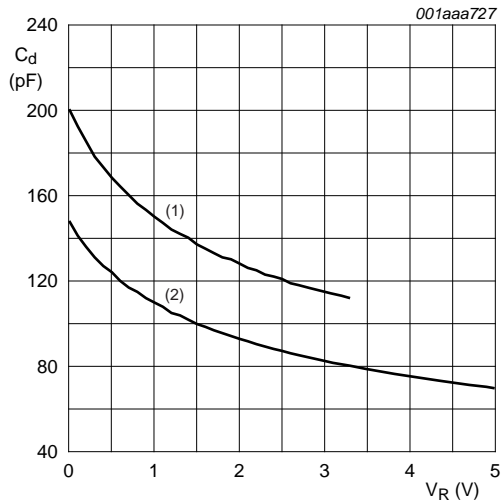


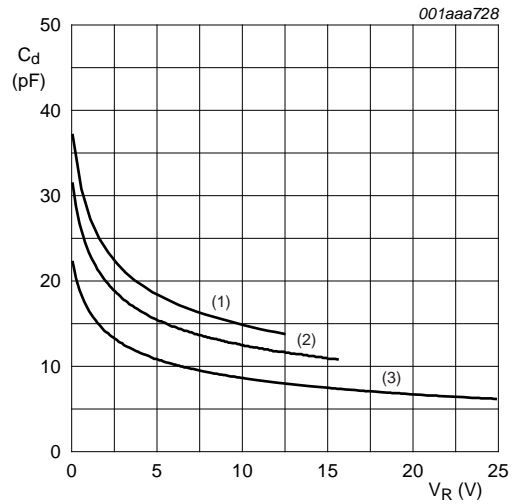
Fig 4. Relative variation of peak pulse power as a function of junction temperature; typical values



$f = 1\text{ MHz}; T_{amb} = 25\text{ }^{\circ}\text{C}$

- (1) PESD3V3S1UL; $V_{RWM} = 3.3\text{ V}$
- (2) PESD5V0S1UL; $V_{RWM} = 5.0\text{ V}$

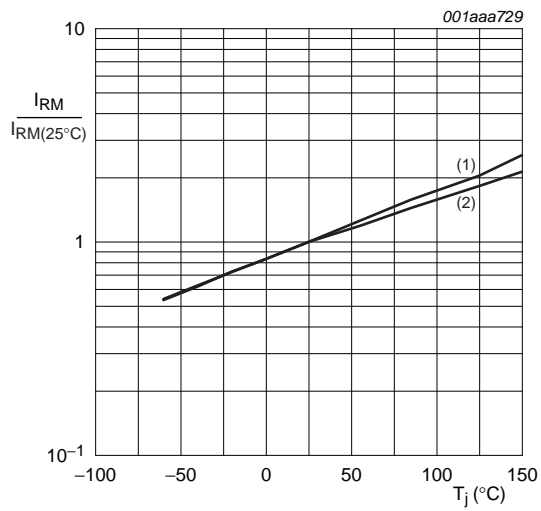
Fig 5. Diode capacitance as a function of reverse voltage; typical values



$f = 1\text{ MHz}; T_{amb} = 25\text{ }^{\circ}\text{C}$

- (1) PESD12VS1UL; $V_{RWM} = 12\text{ V}$
- (2) PESD15VS1UL; $V_{RWM} = 15\text{ V}$
- (3) PESD24VS1UL; $V_{RWM} = 24\text{ V}$

Fig 6. Diode capacitance as a function of reverse voltage; typical values



- (1) PESD3V3S1UL; $V_{RWM} = 3.3\text{ V}$
 - (2) PESD5V0S1UL; $V_{RWM} = 5.0\text{ V}$
- I_R is less than 15 nA at 150 °C for:
- PESD12VS1UL; $V_{RWM} = 12\text{ V}$
 - PESD15VS1UL; $V_{RWM} = 15\text{ V}$
 - PESD24VS1UL; $V_{RWM} = 24\text{ V}$

Fig 7. Relative variation of reverse leakage current as a function of junction temperature; typical values

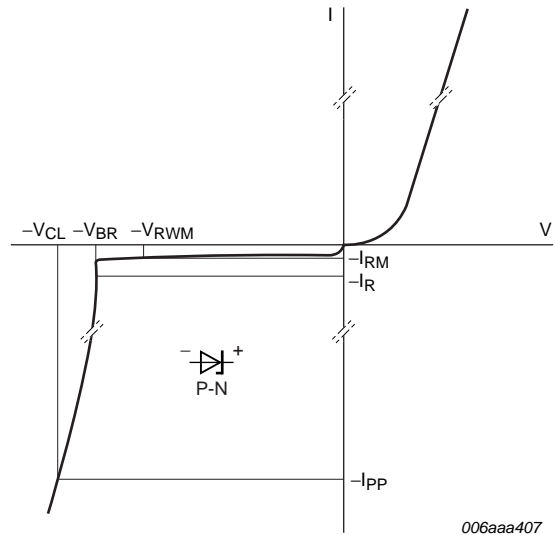
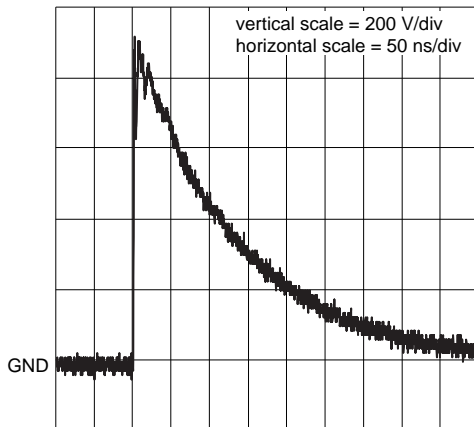
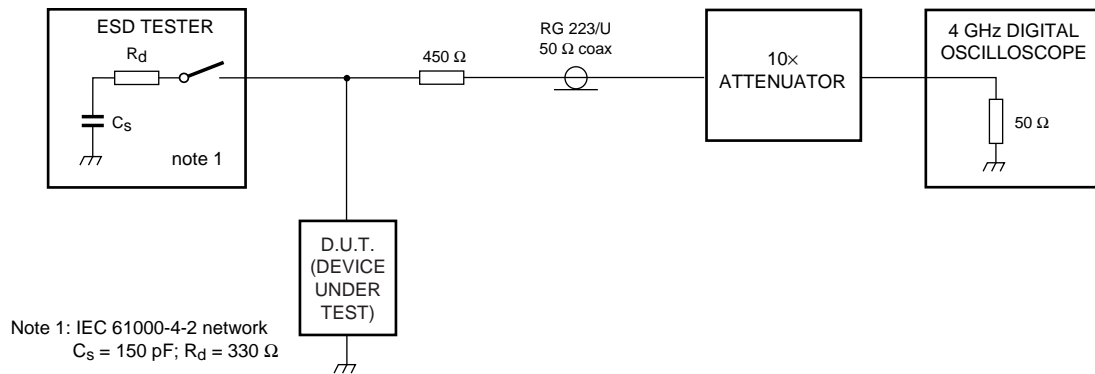
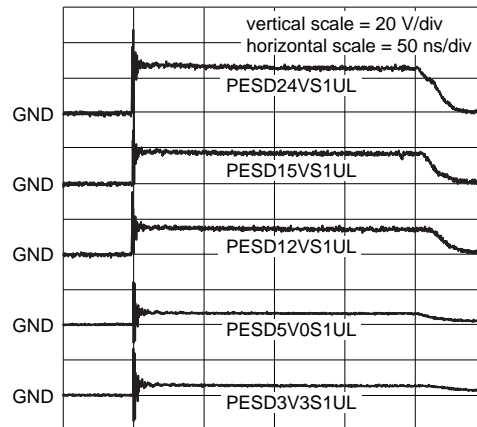


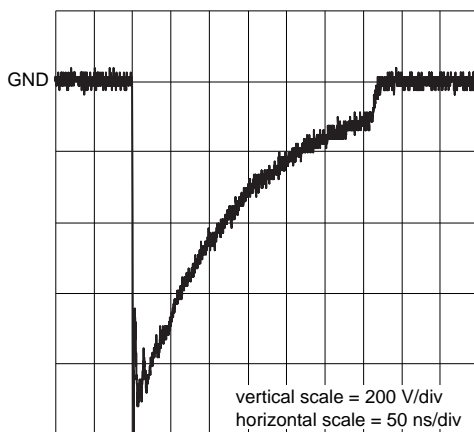
Fig 8. V-I characteristics for a unidirectional ESD protection diode



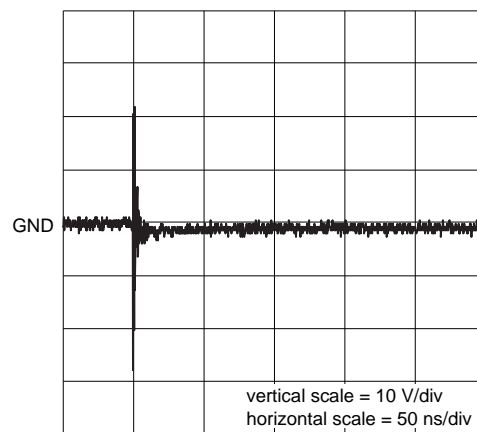
unclamped +1 kV ESD voltage waveform
 (IEC 61000-4-2 network)



clamped +1 kV ESD voltage waveform
 (IEC 61000-4-2 network)



unclamped -1 kV ESD voltage waveform
 (IEC 61000-4-2 network)



clamped -1 kV ESD voltage waveform
 (IEC 61000-4-2 network)

006aaa682

Fig 9. ESD clamping test setup and waveforms

7. Application information

The PESDxS1UL series is designed for protection of one unidirectional data line from the damage caused by ESD and surge pulses. The PESDxS1UL series may be used on lines where the signal polarities are either positive or negative with respect to ground. The PESDxS1UL series provides a surge capability of 150 W for an 8/20 μ s waveform.

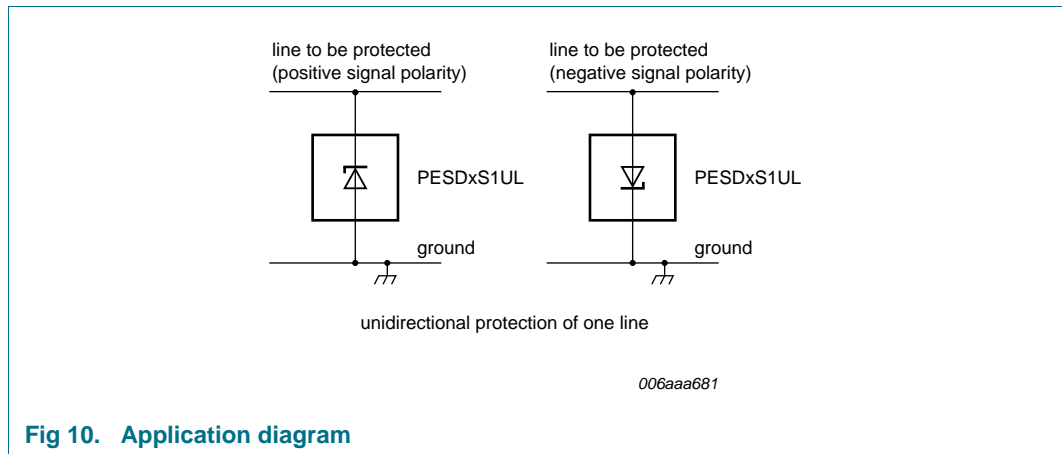


Fig 10. Application diagram

Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

1. Place the PESDxS1UL as close to the input terminal or connector as possible.
2. The path length between the PESDxS1UL and the protected line should be minimized.
3. Keep parallel signal paths to a minimum.
4. Avoid running protected conductors in parallel with unprotected conductors.
5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
6. Minimize the length of the transient return path to ground.
7. Avoid using shared transient return paths to a common ground point.
8. Ground planes should be used whenever possible. For multilayer PCBs, use ground vias.

8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline

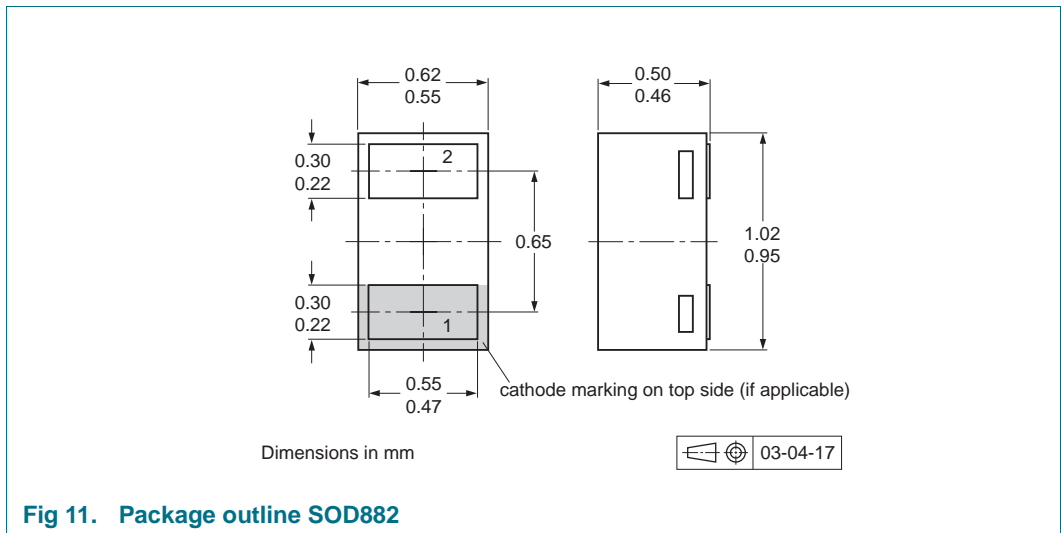


Fig 11. Package outline SOD882

10. Packing information

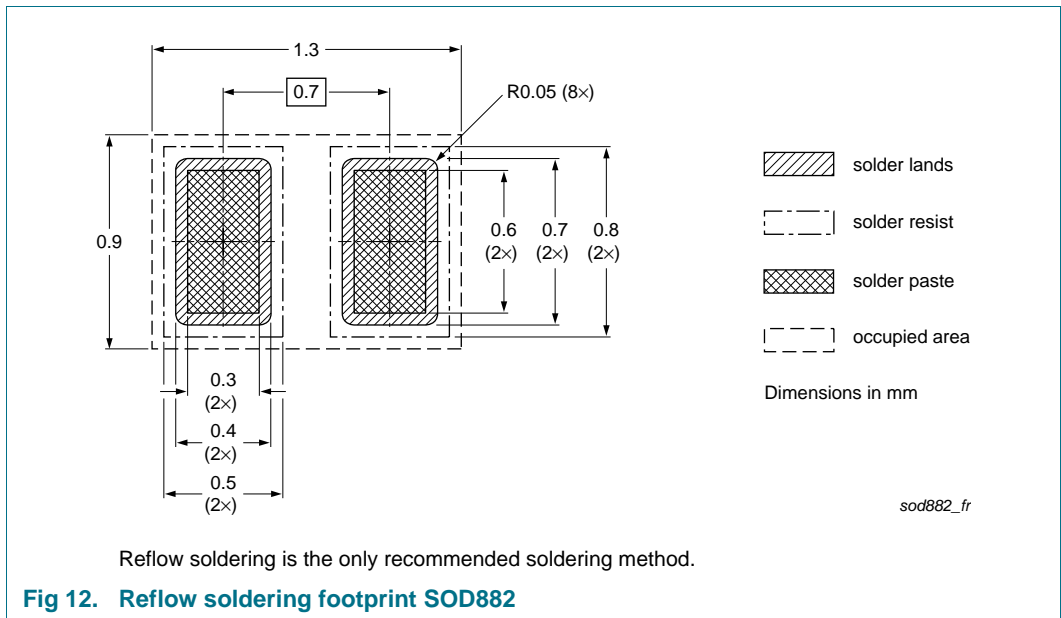
Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.^[1]

Type number	Package	Description	Packing quantity
			10000
PESD3V3S1UL	SOD882	4 mm pitch, 8 mm tape and reel	-315
PESD5V0S1UL			
PESD12VS1UL			
PESD15VS1UL			
PESD24VS1UL			

[1] For further information and the availability of packing methods, see [Section 14](#).

11. Soldering



12. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PESDXS1UL_SER v.3	20111025	Product data sheet	-	PESDXS1UL_SER v.2
Modifications:		<ul style="list-style-type: none">• Section 1.2 "Features and benefits": updated• Table 7: updated• Table 8: added pulse conditions for breakdown voltage V_{BR}• Section 8 "Test information": added• Section 11 "Soldering": added• Section 13 "Legal information": updated		
PESDXS1UL_SER v.2	20090820	Product data sheet	-	PESDXS1UL_SER v.1
PESDXS1UL_SER v.1	20060331	Product data sheet	-	-

13. Legal information

13.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

13.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

13.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or

malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at <http://www.nxp.com/profile/terms>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

13.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

14. Contact information

For more information, please visit: <http://www.nxp.com>

For sales office addresses, please send an email to: salesaddresses@nxp.com

15. Contents

1	Product profile	1
1.1	General description	1
1.2	Features and benefits	1
1.3	Applications	1
1.4	Quick reference data	1
2	Pinning information	2
3	Ordering information	2
4	Marking	2
5	Limiting values	3
6	Characteristics	4
7	Application information	9
8	Test information	9
8.1	Quality information	9
9	Package outline	10
10	Packing information	10
11	Soldering	11
12	Revision history	12
13	Legal information	13
13.1	Data sheet status	13
13.2	Definitions	13
13.3	Disclaimers	13
13.4	Trademarks	14
14	Contact information	14
15	Contents	15

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

© NXP B.V. 2011.

All rights reserved.

For more information, please visit: <http://www.nxp.com>

For sales office addresses, please send an email to: salesaddresses@nxp.com

Date of release: 25 October 2011

Document identifier: PESDxS1UL_SER